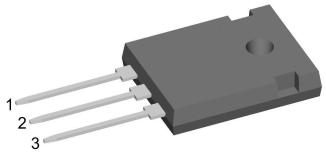
Thyristor

V_{RRM}	=	1400 V
I_{TAV}	=	20 A
V_T	=	1.23 V

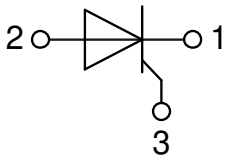
Single Thyristor

Part number

CS20-14io1



Backside: anode



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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Thyristor

Symbol	Definition	Conditions		Ratings min.	typ.	max.	Unit
$V_{RSM/DSM}$	*max. non-repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1500	V
$V_{RRM/DRM}$	*max. repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1400	V
$I_{R/D}$	*reverse current, drain current*	$V_{R/D}$ = 1400 V	T_{VJ} = 25°C			20	µA
		$V_{R/D}$ = 1400 V	T_{VJ} = 125°C			2	mA
V_T	*forward voltage drop*	I_T = 20 A	T_{VJ} = 25°C			1.27	V
		I_T = 40 A				1.53	V
		I_T = 20 A	T_{VJ} = 125°C			1.23	V
		I_T = 40 A				1.57	V
I_{TAV}	*average forward current*	T_C = 130°C	T_{VJ} = 150°C			20	A
$I_{T(RMS)}$	*RMS forward current*	180° sine				31	A
V_{T0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			0.87	V
r_T	*slope resistance* }					17.3	mΩ
R_{thJC}	*thermal resistance junction to case*					0.6	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.3		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			200	W
I_{TSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			260	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			280	A
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			220	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			240	A
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			340	A²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			325	A²s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			240	A²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			240	A²s
C_J	*junction capacitance*	V_R = 400 V f = 1 MHz	T_{VJ} = 25°C		16		pF
P_{GM}	*max. gate power dissipation*	t_P = 30 µs	T_C = 150°C			10	W
		t_P = 300 µs				5	W
P_{GAV}	*average gate power dissipation*					0.5	W
$(di/dt)_{cr}$	*critical rate of rise of current*	T_{VJ} = 125°C; f = 50 Hz	repetitive, I_T = 60 A			150	A/µs
		t_P = 200 µs; di_G/dt = 0.3 A/µs;					
		I_G = 0.3 A; V = ⅔ V_{DRM}	non-repet., I_T = 20 A			500	A/µs
$(dv/dt)_{cr}$	*critical rate of rise of voltage*	V = ⅔ V_{DRM}	T_{VJ} = 125°C			1000	V/µs
		R_{GK} = ∞; method 1 (linear voltage rise)					
V_{GT}	*gate trigger voltage*	V_D = 6 V	T_{VJ} = 25°C			1.3	V
			T_{VJ} = -40°C			1.6	V
I_{GT}	*gate trigger current*	V_D = 6 V	T_{VJ} = 25°C			50	mA
			T_{VJ} = -40°C			80	mA
V_{GD}	*gate non-trigger voltage*	V_D = ⅔ V_{DRM}	T_{VJ} = 125°C			0.2	V
I_{GD}	*gate non-trigger current*					5	mA
I_L	*latching current*	t_p = 10 µs	T_{VJ} = 25°C			150	mA
		I_G = 0.3 A; di_G/dt = 0.3 A/µs					
I_H	*holding current*	V_D = 6 V R_{GK} = ∞	T_{VJ} = 25°C			100	mA
t_{gd}	*gate controlled delay time*	V_D = ½ V_{DRM}	T_{VJ} = 25°C			2	µs
		I_G = 0.3 A; di_G/dt = 0.3 A/µs					
t_q	*turn-off time*	V_R = 100 V; I_T = 20A; V = ⅔ V_{DRM}	T_{VJ} = 125 °C		150		µs
		di/dt = 15 A/µs dv/dt = 20 V/µs t_p = 200 µs					

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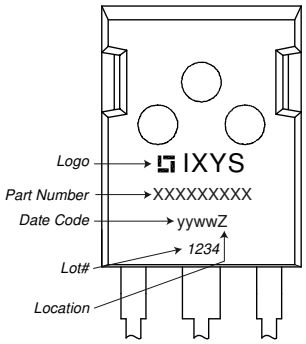
Package TO-247			Ratings			
Symbol	**Definition**	**Conditions**	**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal			70	A
T_{VJ}	*virtual junction temperature*		-40		150	°C
T_{op}	*operation temperature*		-40		125	°C
T_{stg}	*storage temperature*		-40		150	°C
Weight				6		g
M_D	*mounting torque*		0.8		1.2	Nm
F_C	*mounting force with clip*		20		120	N

Product Marking

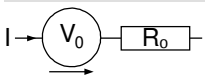


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CS20-14io1	CS20-14io1	Tube	30	466522

Similar Part	Package	Voltage class
CS20-12io1	TO-247AD (3)	1200
CS20-16io1	TO-247AD (3)	1600

Equivalent Circuits for Simulation

** on die level* $T_{VJ} = 150°C$



Thyristor

$V_{0\,max}$	*threshold voltage*	0.87	V
$R_{0\,max}$	*slope resistance **	14.8	mΩ

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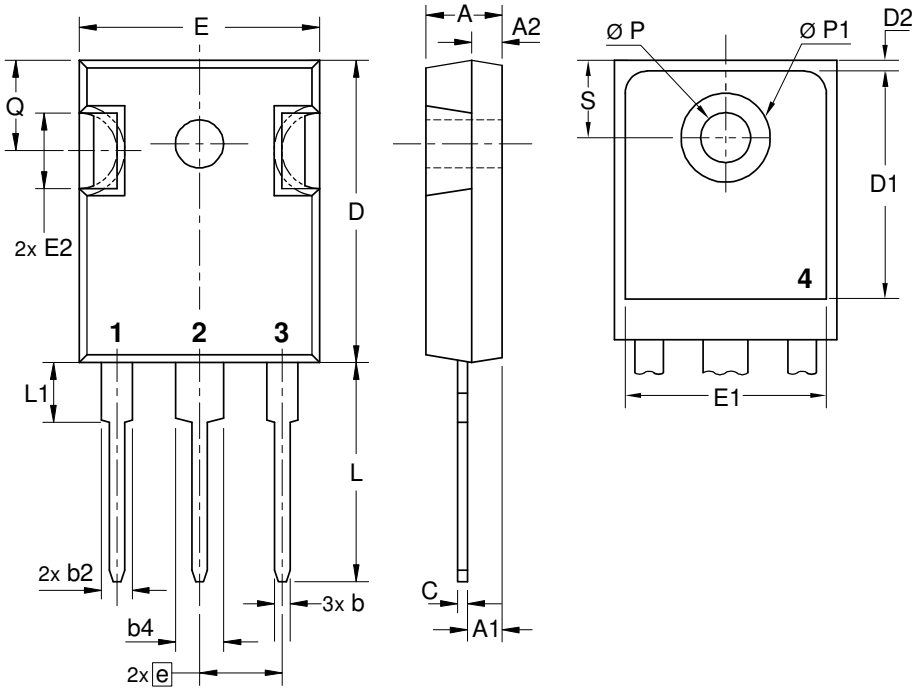
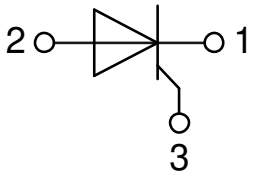
Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39



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Thyristor

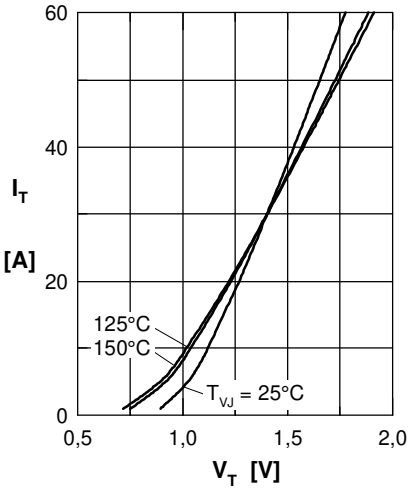

Fig. 1 Forward characteristics

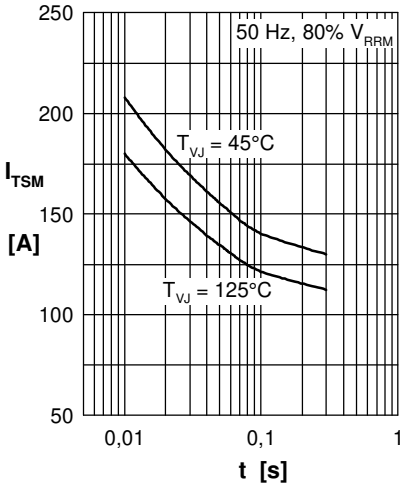

Fig. 2 Surge overload current

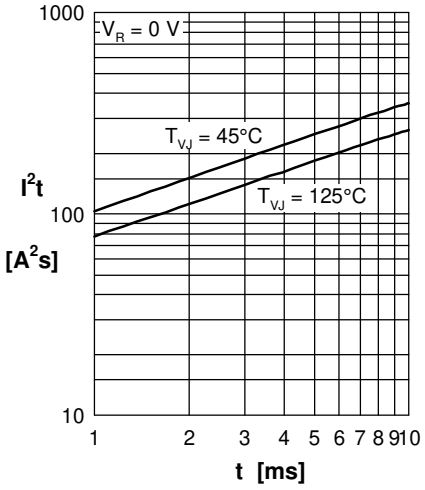

Fig. 3 I^2t versus time (1-10 ms)

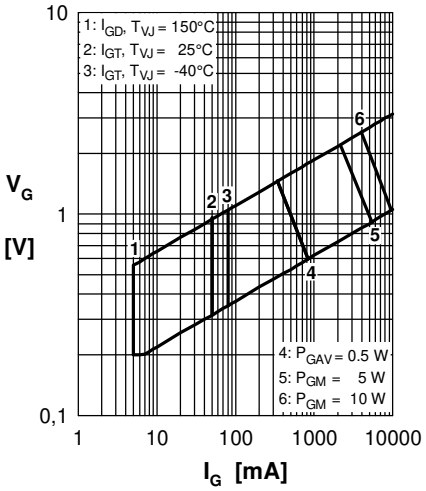

Fig. 4 Gate trigger characteristics

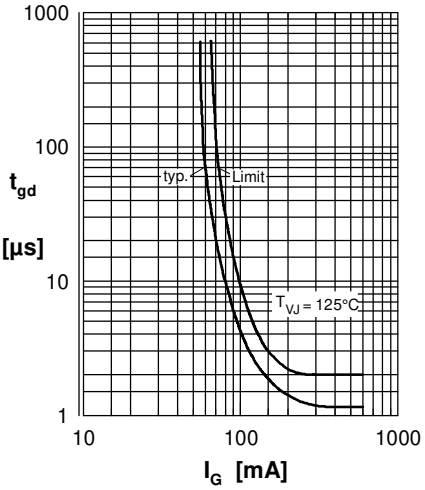

Fig. 5 Gate controlled delay time

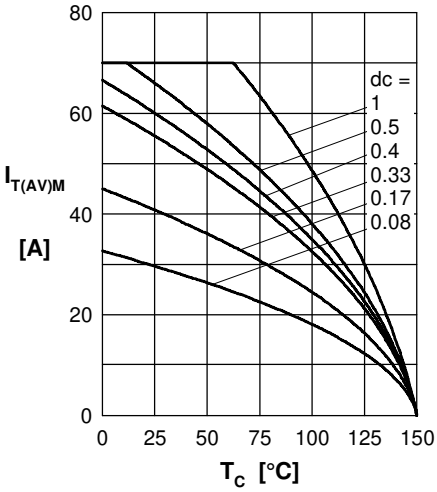

Fig. 6 Max. forward current at case temperature

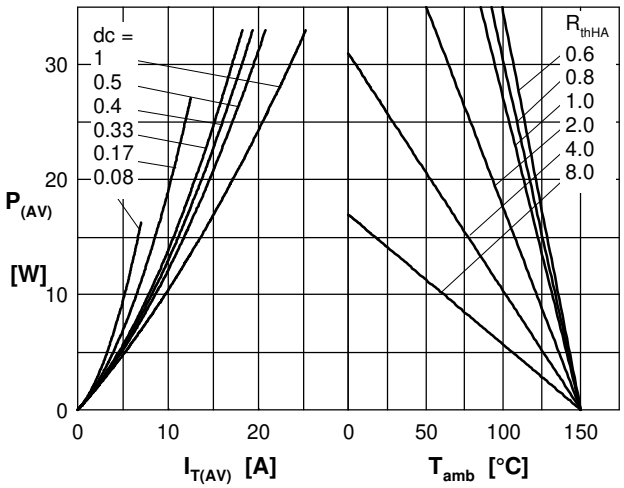

Fig. 7a Power dissipation versus direct output current
Fig. 7b and ambient temperature

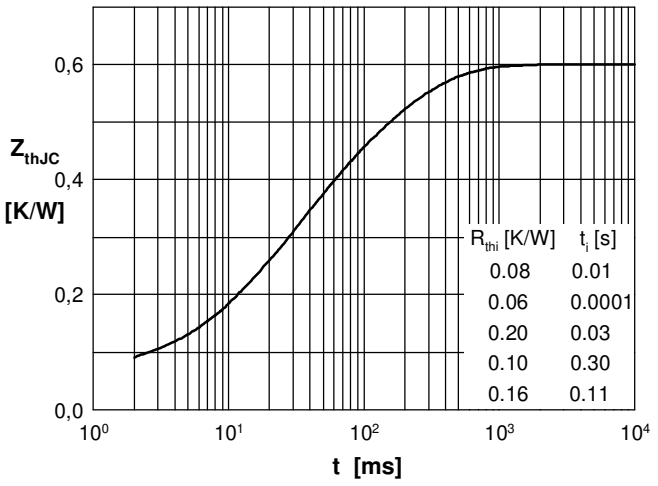

Fig. 8 Transient thermal impedance junction to case

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